L Number	Hits	Search Text	DB	Time stamp
1	216	438/677.ccls.	USPAT	2004/07/13 16:20
2	278	438/681.ccls.	USPAT	2004/07/13 16:20
3	869	438/687.ccls.	USPAT	2004/07/13
4	247	118/638.ccis.	USPAT	2004/07/13
5	97	118/640.ccls.	USPAT	2004/07/13 16:20
6	513	427/508.ccls.	USPAT	2004/07/13
7	92	427/509.ccls.	USPAT	2004/07/13
8	460	427/510.ccls.	USPAT	2004/07/13 16:21
9	19	ueno-kazuyoshi\$.in.	USPAT	2004/07/13
10	11	ueno-kazuyoshi\$.in.	US-PGPUB	2004/07/13
11	121	ueno-kazuyoshi\$.in.	EPO; JPO; DERWENT; IBM_TDB	2004/07/13 16:22
13	7620	vapor\$9 and (electrical and potent\$9) and (CVD chemical) and (power same supply)	USPAT	2004/07/13 16:32
14	2663	(vapor\$9 and (electrical and potent\$9) and (CVD chemical) and (power same supply)) and (electrical same potential)	USPAT	2004/07/13 16:27
15	1950	(vapor\$9 and (electrical and potent\$9) and (CVD chemical) and (power same supply)) and (thermal same (CVD chemical))	USPAT	2004/07/13 16:30
16	1725	((vapor\$9 and (electrical and potent\$9) and (CVD chemical) and (power same supply)) and (thermal same (CVD chemical))) and current	USPAT	2004/07/13 16:31
17	1178	(((vapor\$9 and (electrical and potent\$9) and (CVD chemical) and (power same supply)) and (thermal same (CVD chemical))) and current) and semiconduct\$6	USPAT	2004/07/13 16:31
18	761	vapor\$9 and (electrical same potent\$9) and (CVD chemical) and (power same supply) and semiconduct\$6	US-PGPUB	2004/07/13 16:32
19	2	vapor\$9 and (electrical same potent\$9) and (CVD chemical) and (power same supply) and semiconduct\$6	EPO; JPO; DERWENT; IBM_TDB	2004/07/13 16:32
20	5	vapor\$9 and (electrical same potent\$9) and (CVD chemical) and (power same supply)	EPO; JPO; DERWENT; IBM_TDB	2004/07/13 16:33
21	9	thermal and (electrical and potent\$9) and (CVD chemical) and (power and supply)	EPO; JPO; DERWENT; IBM_TDB	2004/07/13 16:34

22	693	vapor\$9 and (CVD chemical) and (power and	EPO; JPO;	2004/07/13
		supply)	DERWENT;	16:34
			IBM TDB	